

DOE16_LDMOS_8X400um = 3,2mm Simulation

Minipac design

Build #8

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15.08.2022

Last updated
16.08.2022

- restricted -

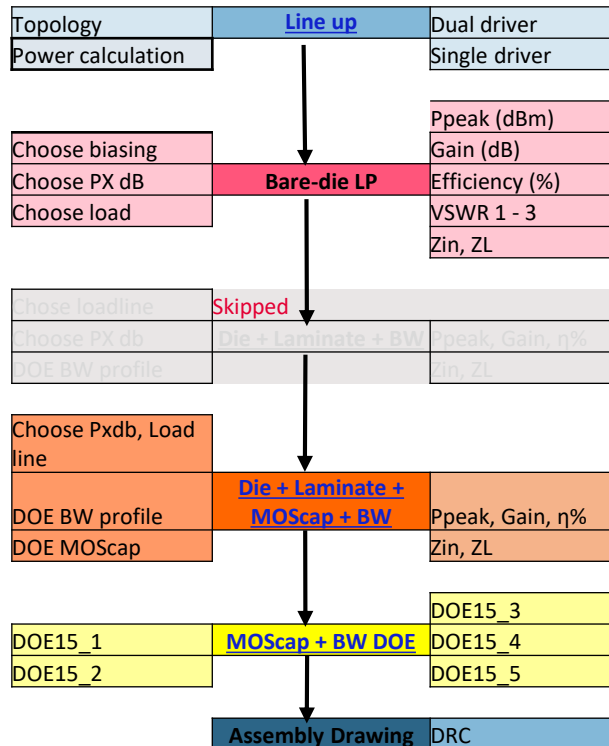


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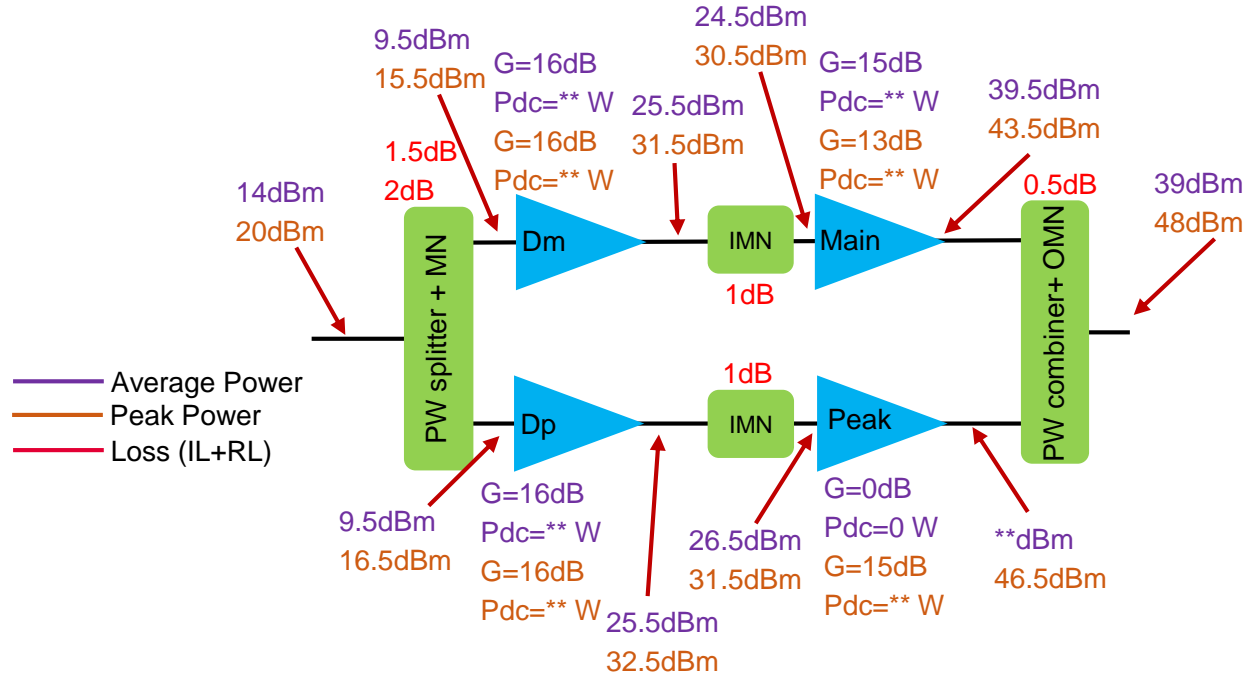
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Design approach

- > Step 1: Line up calculation with losses
- > Step 2: Obtain Main section driver power requirement
- > Step 3: Choose the available LDMOS die that delivers the power
- > Step 4: Design/performance criteria
 - > Compression X dB <1,
 - > Px dB > 36 dBm
 - > As high Gt as possible
 - > As high η % as possible
- > Bondwire + Moscap to improve performance
 - > Select Moscap DOE



From: Dual driver Architecture-Draft (Alireza)

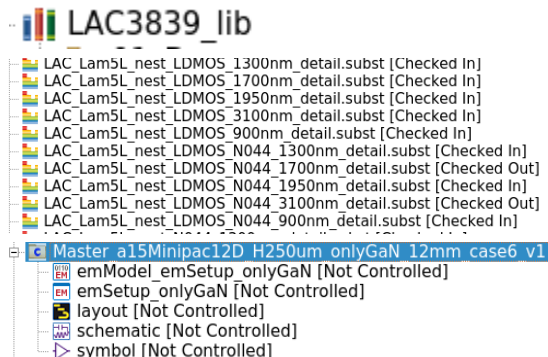


- › Around 35.5 dBm expected to drive peak input
- › Intended to operate in as much linear region as possible until $P_{out} = 35.5\text{ dBm}$



Design on laminate DOE15

› Laminate library:LAC3839_lib



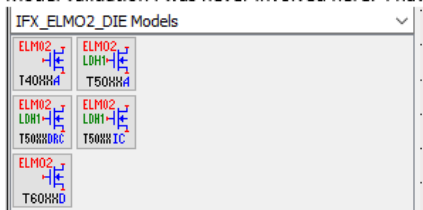
	LDMOS	MOSCap
Design	Die_LDMOS_v0_lib	IC_LD8C_lib
Assembly drawing	Die_LDMOS_v0_lib	Central_v0_lib



LDMOS model

LDMOS models,

- Model validation I was never involved here. I have the model itself, and we could theoretically even support and improve this in the future, but I don't have validation data or report.



You need to go to the 'ELMO2' palette (there are many palettes)

T40xx = LD10

T60xx = LD12 (LD10S)

Anything marked with LH1 is 50V LDMOS – poor performance >1GHz.

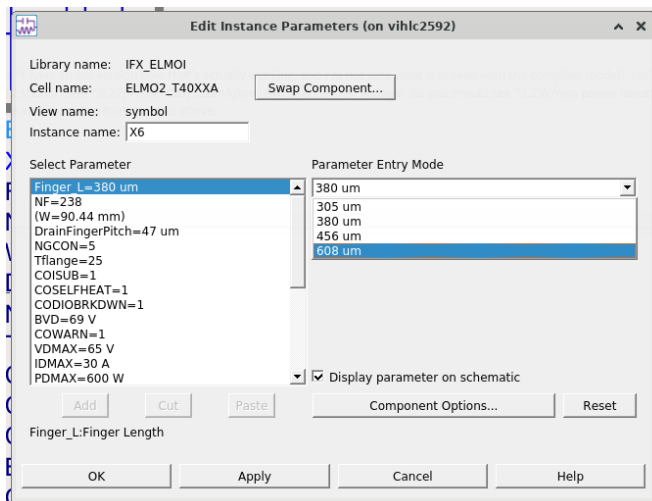
I believe the LD11 model was discontinued – and in any case for a plastic OM product we shouldn't consider LD11.

\\mucsdv534.infineon.com\RFS\PG_WI\90_TechInfo\LDMOS\PKD_Model



Design Notes

Right Finger length is not Available, So only 2.28 mm can be made (Interested 2.4mm)



Fab Name	Marketing Name	Comment
LD10M	LD10	Oldest run material, Sinkers (no TSV) and no voids
LD10E	LD11	LD10M with 'open' voids. Not suitable for plastic
LD10S	LD12	High res+TSV and integrated capped voids for low Cds.

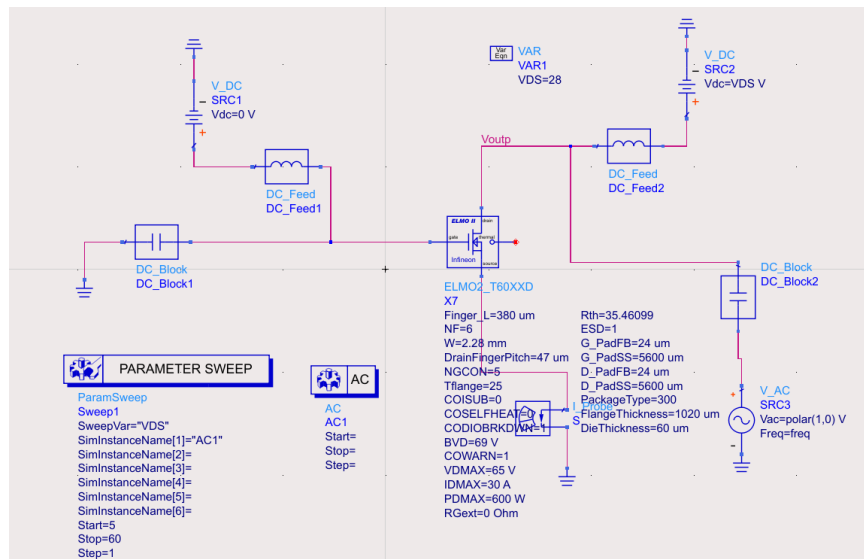
So if you are using LD10S, this is not the same thing as LD10.



CDS checking

N.B. I don't have an old version now that's actually working, and I'm not sure what is broken with the compiled model! Let's look carefully at the results you get.

N.B. LD12 should have ~0.27pF/mm Cds, 110mA/mm ISAT and 28V rail voltage. So you should see ~1.2W/mm power density and the Cout should let you roughly estimate the load contours. If you get strange results you should be able to realise from number above.

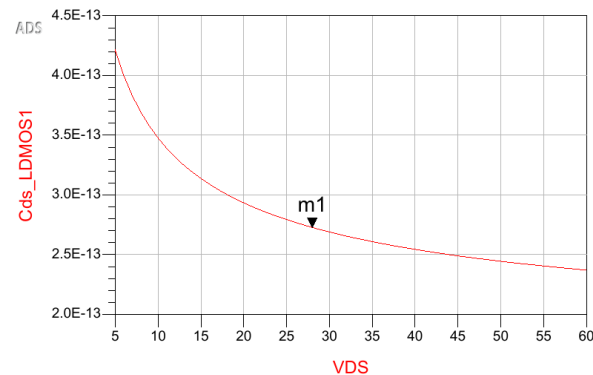


$$\text{Eqn} Z_{out_p} = V_{outp}/S.i$$

$$\text{Eqn} C_{ds_LDMOS1} = 1/(2*4.56*pi*AC.freq*-imag(Z_{out_p}))$$

```

m1
indep(m1)=28.000
plot_vs(Cds_LDMOS1,VDS)=2.728E-13
freq=3.600E9
  
```



DOE_16 variants

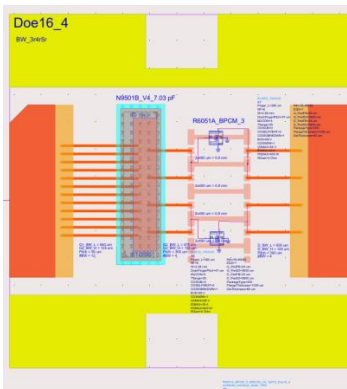
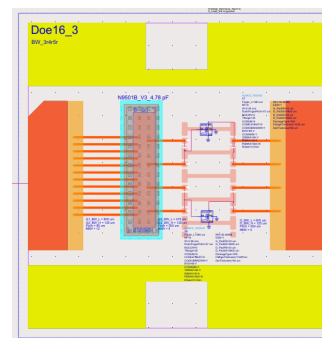
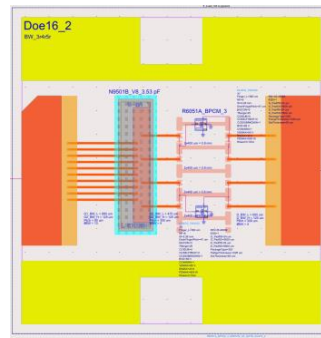
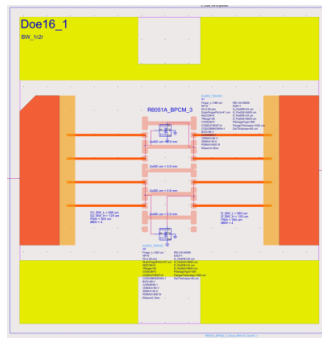
LDMOS_A (4x0.8mm = 3,2mm)	P_1dB	Moscap_detail_EM					Max. performance @ P1dB			Performance_@ (35,0 dBm)						Performance_@ (36 dBm)					
		Name	RF top plate (X x Y)	Oxide thickness (µm)	Value (pF)		Freq.	MXP (dBm)	MXG (dB)	MXE (%)	Zin (Ω)	Z_L (Ω)	Pout (dBm)	Eff. (%)	Gt (dB)	IRL (dB)	Zin (Ω)	Z_L (Ω)	Pout (dBm)	Eff. (%)	Gt (dB)
DOE_16	BW_profile	Direct				3.6 GHz	36,8	18,8	57,0	3,9 + j 2,2	1,9 + j 7,3	35,42	56,6	17,9	-17,5	3,9 + j 1,7	2,8 + j 6,7	36,64	55,6	17,0	-18,1
DOE_16_1	BW_1q_2q	N9501B_V8		3100	3,53	3.6 GHz	36,7	17,5	52,9	3,1 + j 2,7	2,7 + j 8,7	35,6	50,8	16,8	-19,7	3,0 + j 2,6	3,4 + j 8,2	36,36	50,1	16,2	-21,2
DOE_16_2	BW_3q_4q_5q	N9500B_V7		3100	4,64	3.6 GHz	36,9	17,5	50,8	2,5 + j 1,8	2,7 + j 8,7	35,69	50,7	16,8	-17,3	2,4 + j 1,7	3,4 + j 8,3	36,54	50,2	16,0	-16,3
DOE_16_3	BW_3q_4q_5q	N9500B_V2		1950	5,41	3.6 GHz	37,1	17,5	51,2	1,9 + j 2,1	2,7 + j 8,7	35,84	51,1	16,7	-15,2	1,8 + j 2,0	3,4 + j 8,3	36,67	50,7	16,0	-14,4
DOE_16_4	BW_3q_4q_5q	N9500B_Std		1950	6,18	3.6 GHz	37,2	17,2	53,8	1,5 + j 2,3	2,4 + j 8,7	35,39	50,9	16,8	-11,7	1,4 + j 2,2	3,4 + j 8,2	36,77	51,1	15,7	-11,1

Compression = 1, ClassAB, Moscap: Detail EM



ADS cells and symbols

- R6051A_BPCM_3_Direct_BW1r2r_Doe16_1
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 - emSetup_detail [Checked In]
 - layout [Checked In]
 - layout_assy [Checked In]
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 - symbol [Checked In]
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Acknowledgements

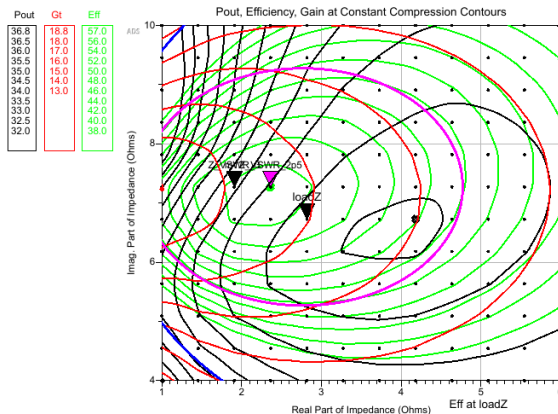
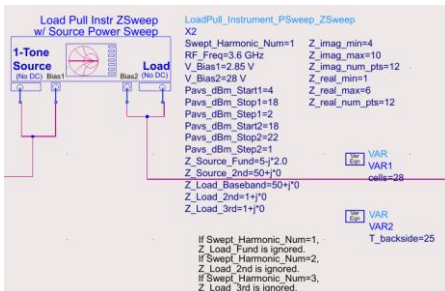
- › [Theepak ShoundraBalan](#): Design related discussions, design review, troubleshooting and debugging.
- › [Fillippo Panzalo](#): EM layouts of Moscaps, LDMOS dies, Assembly drawing generation and review, EM simulation support.
- › [Jorge Texeira](#): Assembly design rule guidelines, drawing review, build planning, coordination and documentation.
- › [Shamsafar Alireza](#): Design review, design target discussions and guidelines.
- › [De Astis Giuseppe](#) & [Andrea Scarpa](#): Design follow up, design environment & logistic coordination.





Part of your life. Part of tomorrow.

Direct Moscapy; Detailed 3,6GHz



Power Sweep Inspector

VSWRVal=5 VSWRVal=2.5

Move Marker 'loadZ' to desired impedance point.

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $4.18 + j6.73$
VSWR=5

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $1.91 + j7.27$
VSWR=5

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.82 + j6.73$	$0.90 / 164.63$	1
Pout (dBm)	Eff (%)	Gt (dB)
36.64	55.50	17.03
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-6.68	-18.13	$3.94 + j1.68$

✗ In plots below corresponds to this data.

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$1.91 + j7.27$	$0.93 / 163.42$	1
Pout (dBm)	Eff (%)	Gt (dB)
35.42	56.62	17.90
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-9.04	-17.51	$3.85 + j2.18$

✗ In plots below corresponds to this data.

VSWR = 2.5 point DATA

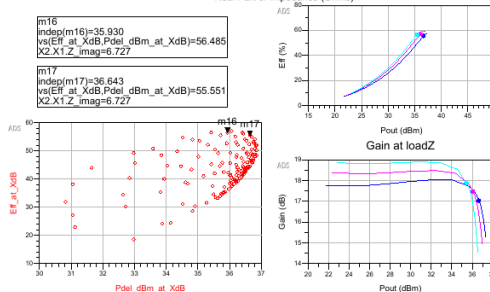
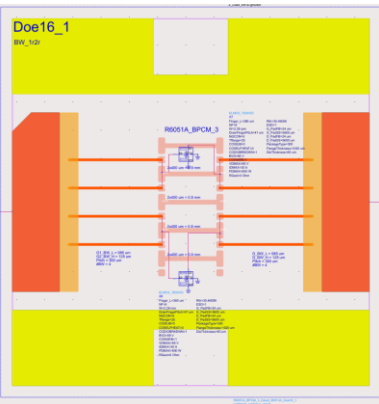
Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.36 + j7.27$	$0.91 / 163.41$	1
Pout (dBm)	Eff (%)	Gt (dB)
36.06	57.06	17.48
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.54	-19.27	$4.02 + j1.98$

✗ In plots below corresponds to this data.

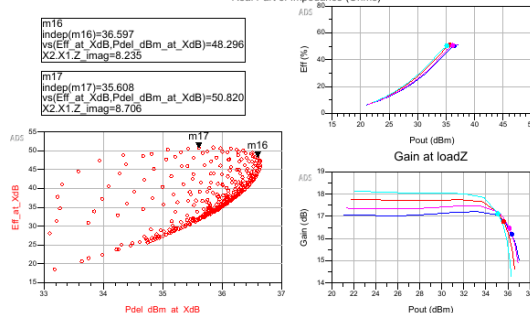
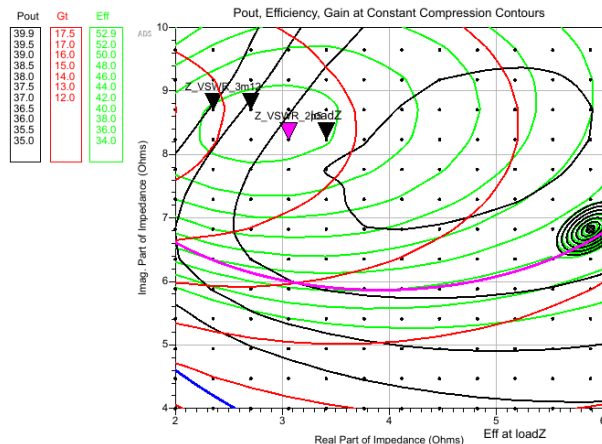
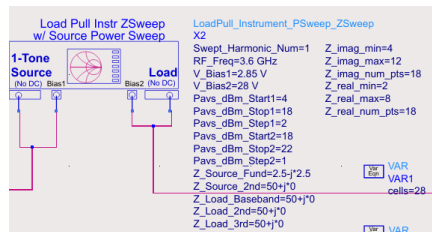
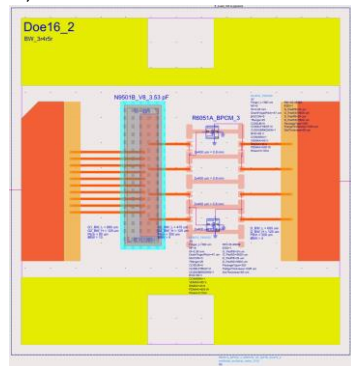
VSWR = 3 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$1.91 + j7.27$	$0.93 / 163.42$	1
Pout (dBm)	Eff (%)	Gt (dB)
35.42	56.62	17.90
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-9.04	-17.51	$3.85 + j2.18$

✗ In plots below corresponds to this data.



C=3p53pF
Moscapy: Detailed
3,6GHz



Power Sweep Inspector

VSWRVal=5 VSWRVal=2.5

Move Marker 'loadZ' to desired impedance point.

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $5.88 + j6.82$
VSWR=5

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $2.71 + j8.71$
VSWR=5

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$3.41 + j8.24$	$0.88 / 161.21$	1
Pout (dBm)	Eff (%)	Gt (dB)
36.36	50.13	16.20
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-6.42	-21.21	$2.97 + j2.56$

✗ In plots below corresponds to this data.

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.71 + j8.71$	$0.90 / 160.19$	1
Pout (dBm)	Eff (%)	Gt (dB)
35.61	50.82	16.78
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.16	-19.69	$3.05 + j2.69$

✗ In plots below corresponds to this data.

VSWR = 2.5 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$3.06 + j8.24$	$0.89 / 161.23$	1
Pout (dBm)	Eff (%)	Gt (dB)
36.14	50.66	16.46
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.65	-21.16	$2.96 + j2.64$

✗ In plots below corresponds to this data.

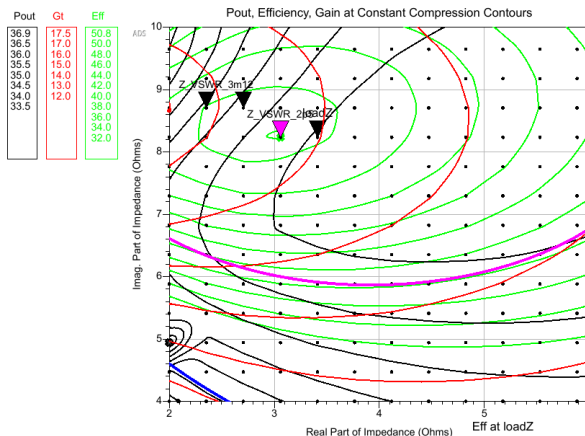
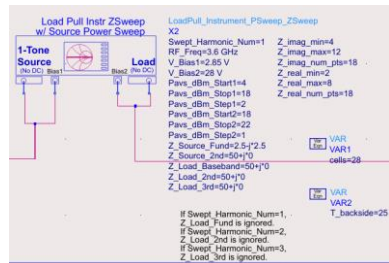
VSWR = 3 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.35 + j8.71$	$0.91 / 160.20$	1
Pout (dBm)	Eff (%)	Gt (dB)
35.08	50.35	17.12
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.94	-19.40	$3.03 + j2.77$

✗ In plots below corresponds to this data.

DOE16_03

C=4p78pF
Moscapy: Detailed
3,6GHz



Power Sweep Inspector

Eqn VSWRVal=5 Eqn VSWRVal=2.5

Move Marker 'loadZ' to desired impedance point.

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $2.00 + j4.94$
VSWR=5

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $2.71 + j8.71$
VSWR=5

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$3.41 + j8.24$	$0.88 / 161.21$	1
Pout (dBm)	Eff (%)	Gt (dB)
36.54	50.23	16.03
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-6.49	-16.31	$2.42 + j1.74$

✗ In plots below corresponds to this data.

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.71 + j8.71$	$0.90 / 160.19$	1
Pout (dBm)	Eff (%)	Gt (dB)
35.69	50.69	16.76
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-6.91	-17.26	$2.48 + j1.81$

✗ In plots below corresponds to this data.

VSWR = 2.5 point DATA

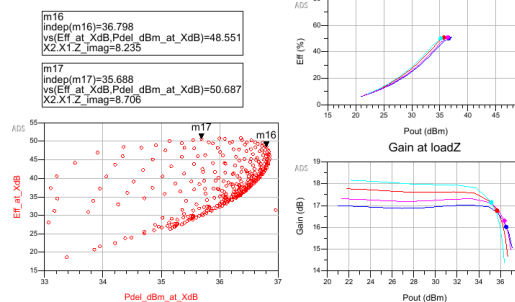
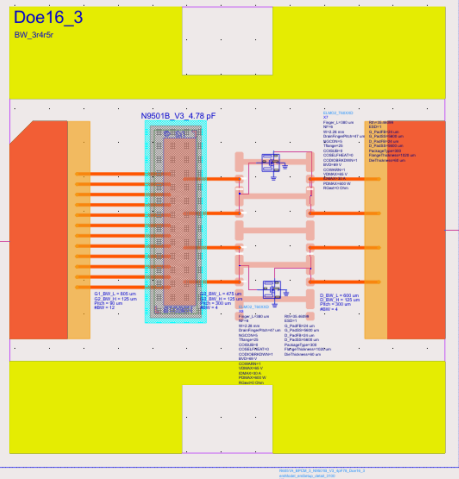
Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$3.06 + j8.24$	$0.89 / 161.23$	1
Pout (dBm)	Eff (%)	Gt (dB)
36.36	50.87	16.31
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.94	-17.01	$2.42 + j1.80$

✗ In plots below corresponds to this data.

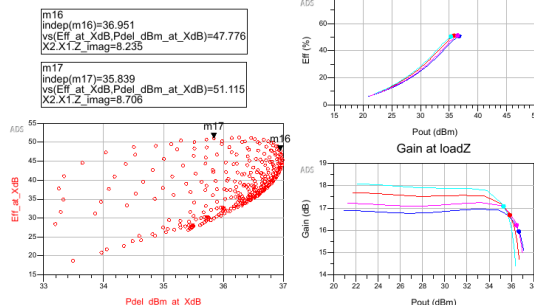
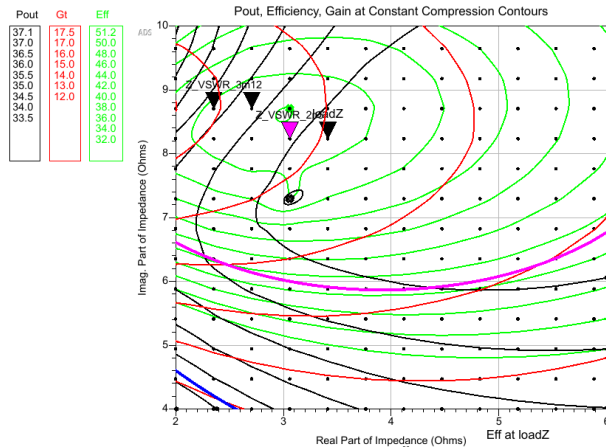
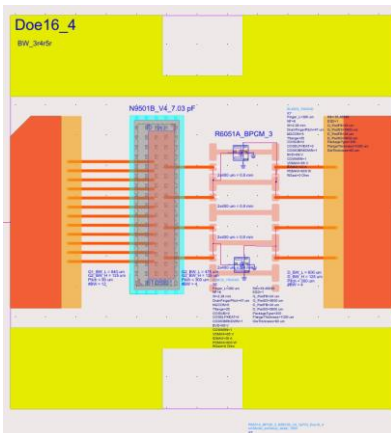
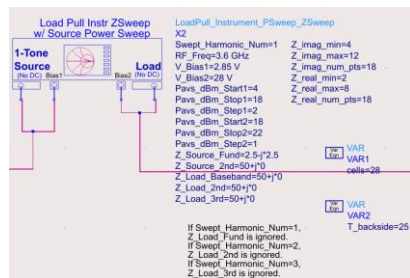
VSWR = 3 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.35 + j8.71$	$0.91 / 160.20$	1
Pout (dBm)	Eff (%)	Gt (dB)
35.14	50.13	17.15
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.65	-18.11	$2.47 + j1.88$

✗ In plots below corresponds to this data.



C=5p41pF
Moscapy: Detailed
3,6GHz



Power Sweep Inspector

Egn VSWRVal=5 Egn VSWRVal1=2.5

Move Marker 'loadZ' to desired impedance point.

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $3.06 + j7.29$
VSWR=5

VSWR Locus of Points selector is located on Constant Compression Loadpull page.

VSWR Locus center Impedance = $2.71 + j8.7$
VSWR=5

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
3.41 + j8.24	0.88 / 161.21	1
Pout (dBm)	Eff (%)	Gt (dB)
36.67	50.68	15.95
AMPM (dBm)	IRL (dB)	Zin (Ohm)
-6.21	-14.40	1.83 + j2.02

X In plots below corresponds to this data.

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
2.71 + j8.71	0.90 / 160.19	1
Pout (dBm)	Eff (%)	Gt (dB)
35.84	51.12	16.69
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-6.72	-15.19	1.88 + j2.05

X In plots below corresponds to this data.

VSWR = 2.5 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
3.06 + j8.24	0.89 / 161.23	1
Pout (dBm)	Eff (%)	Gt (dB)
36.46	51.16	16.24
AMPM (dBm)	IRL (dB)	Zin (Ohm)
-7.43	-14.65	1.83 + j2.06

X In plots below corresponds to this data.

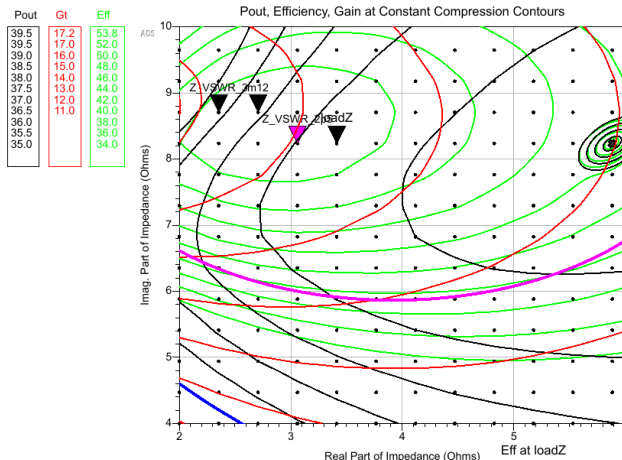
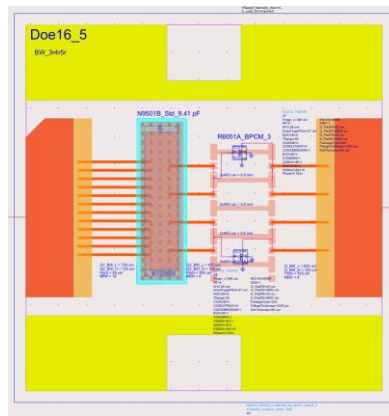
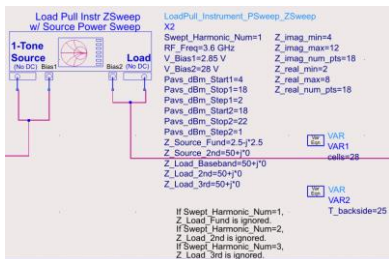
VSWR = 3 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
2.35 + j8.71	0.91 / 160.20	1
Pout (dBm)	Eff (%)	Gt (dB)
35.29	50.50	17.08
AMPM (dBm)	IRL (dB)	Zin (Ohm)
-7.53	-15.52	1.88 + j2.10

X In plots below corresponds to this data.

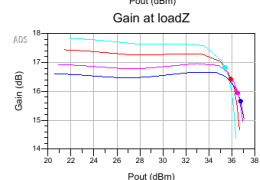
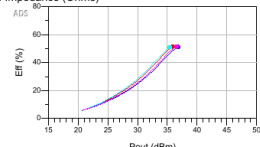
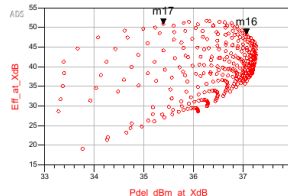
DOE16_05

C=6p18pF
Moscapy: Detailed
3,6GHz



m16
Indep(m16)=37.070
vs(Eff_at_XdB_Pdel_dBm_at_XdB)=48.309
X2.X1.Z_imag=8.235

m17
Indep(m17)=35.391
vs(Eff_at_XdB_Pdel_dBm_at_XdB)=50.938
X2.X1.Z_imag=8.706



Power Sweep Inspector

VSWRVal=5 VSWSVal=2.5

Move Marker 'loadZ' to desired impedance point.

VSWS Locus of Points selector is located on Constant Compression Loadpull page.

VSWS Locus center Impedance = $5.88 + j8.24$
VSWS=5

VSWS Locus of Points selector is located on Constant Compression Loadpull page.

VSWS Locus center Impedance = $2.71 + j8.71$
VSWS=5

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$3.41 + j8.24$	0.88 / 161.21	1
Pout (dBm)	Eff (%)	Gt (dB)
36.77	51.13	15.65
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-6.33	-11.08	$1.43 + j2.22$
✗ In plots below corresponds to this data.		

Summary of Performance at Compression

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.71 + j8.71$	0.90 / 160.19	1
Pout (dBm)	Eff (%)	Gt (dB)
35.91	51.48	16.42
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-6.89	-11.56	$1.48 + j2.24$
✗ In plots below corresponds to this data.		

VSWS = 2.5 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$3.06 + j8.24$	0.89 / 161.23	1
Pout (dBm)	Eff (%)	Gt (dB)
36.52	51.48	15.95
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.42	-11.15	$1.44 + j2.25$
✗ In plots below corresponds to this data.		

VSWS = 3 point DATA

Marker Impedance	Marker Gamma	Reference Compression Level (dB)
$2.35 + j8.71$	0.91 / 160.20	1
Pout (dBm)	Eff (%)	Gt (dB)
35.39	50.94	16.82
AMPm (dBm)	IRL (dB)	Zin (Ohm)
-7.90	-11.74	$1.49 + j2.28$
✗ In plots below corresponds to this data.		

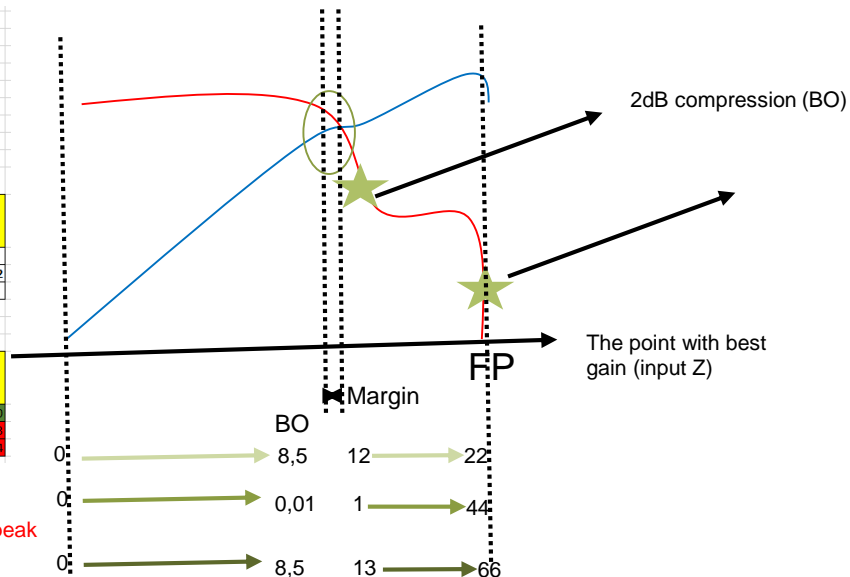


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Power calculation: Asymmetric Doherty

Specification									
Project	Frequency-Range (MHz)	P3dB (dBm)	P3dB (W)	PAR					
PAM 2.0+	3400 - 3800		47,4	54,95	8,4				
		Pavg (dBm)	Pavg (W)						
			39	7,94					
Doherty Topology	Remark	Ratio	Main (W)	Peak (W)					
2-way asymmetric	To maximize efficiency		2	18,32	36,64				
Estimation including loss									
	Required power (W)	Required power (dBm)	Loss (dBm)	Total required power (dBm)	Total required power (W)	Ratio	Total power (W)	Total power (dBm)	
Main	18,32	42,63	0,8	43,43	22,02		3,01	66,07	48,20
Peak	36,64	45,64	0,8	46,44	44,05				
	Total output power (dBm)	PAR	Power @ MXE (dBm)	Margin (dB)	Power @ MXE (dB)	Power @ MXE (W)	MXP (W)	MXP(dBm)	
Main	48,2	8,4	39,8	1,00	40,80	12,02	22,02	43,43	48,20
Peak			Peak_start ideal		Peak start	0,01	44,05	46,44	46,44

Required power from peak



Maximize Gain

- Main section gain as high as possible while maintaining Power @ MXE
- Peak section gain as high as possible while maintaining MXP

